

Vishay Siliconix

Automotive P-Channel 40 V (D-S) 175 °C MOSFET

DESCRIPTION

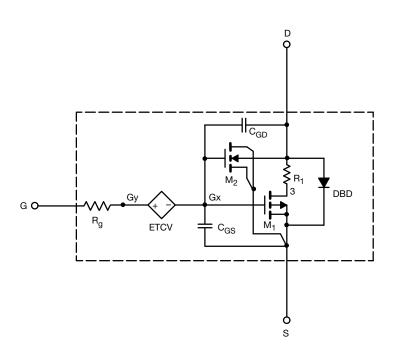
The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 °C to 125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- P-channel vertical DMOS
- Macro model (subcircuit model)
- Level 3 MOS
- Apply for both linear and switching application
- Accurate over the -55 °C to 125 °C temperature range
- Model the gate charge

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits



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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-source threshold voltage	V _{GS(th)}	$V_{DS}=V_{GS},\ I_{D}=-250\ \mu A$	2	-	V
Drain-source on-state resistance ^a	Р	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -10 \text{ A}$	0.0114	0.0115	Ω
	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -6 \text{ A}$	0.0170	0.0163	
Forward transconductance ^a	g _{fs}	$V_{DS} = -15 \text{ V}, \text{ I}_{D} = -10 \text{ A}$	38	37	S
Diode forward voltage	V _{SD}	I _S = -10 A	-0.80	-0.82	V
Dynamic ^b					
Input capacitance	C _{iss}	V_{DS} = -25 V, V_{GS} = 0 V, f = 1 MHz	4670	4405	pF
Output capacitance	C _{oss}		199	248	
Reverse transfer capacitance	C _{rss}		183	234	
Total gate charge	Qg	$V_{DS} = -20 \text{ V}, \text{ V}_{GS} = -10 \text{ V}, \text{ I}_{D} = -2.5 \text{ A}$	63	63	nC
Gate-source charge	Q _{gs}		13	9.5	
Gate-drain charge	Q _{gd}		9	9.5	

Notes

a. Pulse test; pulse width $\leq 300~\mu\text{s},\,duty~cycle \leq 2~\%$

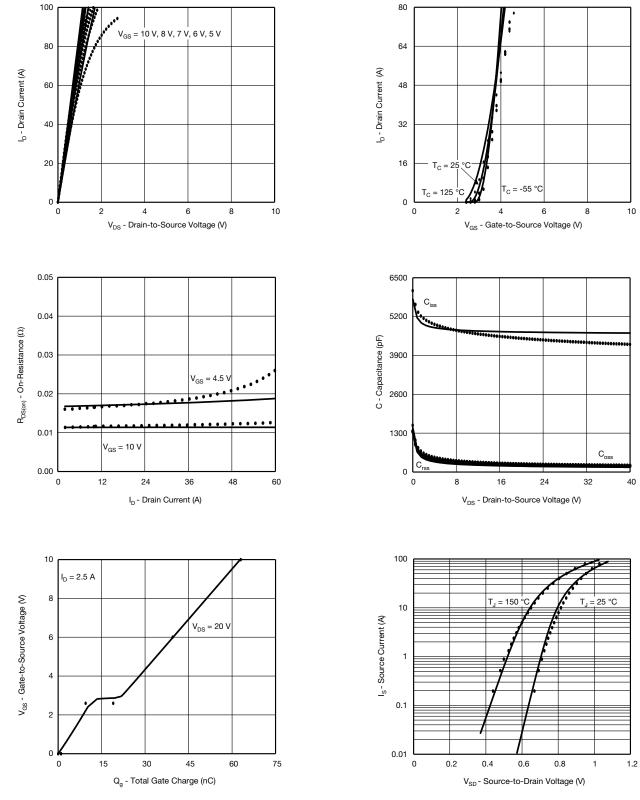
b. Guaranteed by design, not subject to production testing

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COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)



Note

• Dots and squares represent measured data Copyright: Vishay Intertechnology, Inc.

S18-0691-Rev. A, 09-Jul-2018

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Document Number: 76096

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